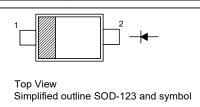
# Silicon Epitaxial Planar Switching Diode

#### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



## Absolute Maximum Ratings ( $T_a = 25$ °C)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage		$V_{RRM}$	85	V
Reverse Voltage		$V_R$	75	V
Continuous Forward Current	l <sub>F</sub>	250	mA	
Repetitive Peak Forward Current		I <sub>FRM</sub>	500	mA
Non-repetitive Peak Forward Surge Current	at t = 1 s at t = 1 ms at t = 1 µs	I <sub>FSM</sub>	0.5 1 4	Α
Power Dissipation		P <sub>tot</sub>	400	mW
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	- 65 to + 150	°C

#### **Thermal Characteristics**

Parameter	Symbol	Max.	Unit	
Thermal Resistance from Junction to Ambient 1)	$R_{ heta JA}$	313	°C/W	

<sup>1)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



## **BAS216W**

## Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at I <sub>R</sub> = 10 μA	$V_{(BR)R}$	75	-	V
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	V <sub>F</sub>		0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 25 \text{ V}$ , $T_j = 150^{\circ}\text{C}$ at $V_R = 75 \text{ V}$ , $T_j = 150^{\circ}\text{C}$	I <sub>R</sub>		30 1 30 50	n A A A A A A
Diode Capacitance at $V_R = 0 V$ , $f = 1 MHz$	C <sub>tot</sub>	-	1.5	pF
Reverse Recovery Time at $I_F$ = 10 mA, $I_{rr}$ = 0.1 X $I_R$ , $V_R$ = 6 V, $R_L$ = 100 $\Omega$	t <sub>rr</sub>	-	4	ns



#### **Electrical Characteristics Curves**

Fig 1. Power Derating Curve

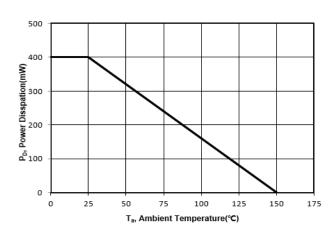


Fig 2. Capacitance Characteristics

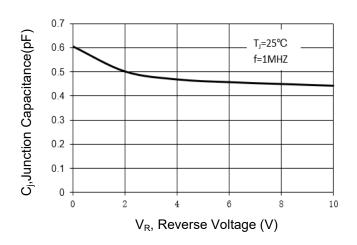


Fig 3. Reverse Characteristics

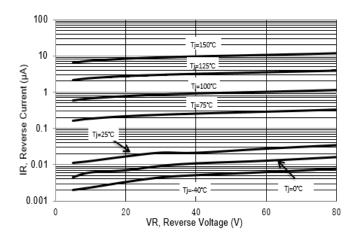
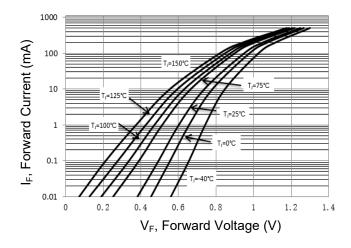


Fig 4. Forward Characteristics

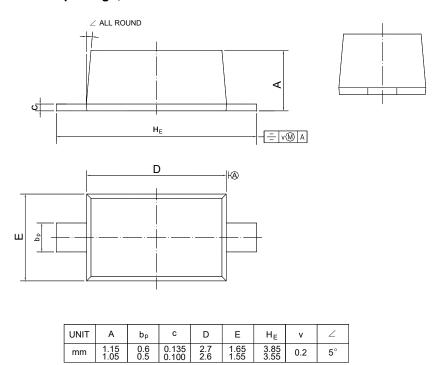




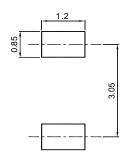
#### **PACKAGE OUTLINE**

#### Plastic surface mounted package; 2 leads

**SOD-123** 



## **Recommended Soldering Footprint**



#### **Packing information**

i acking information								
	Package	Tape Width	Pitch		Reel Size		Per Reel Packing Quantity	
	rackage	Fackage	(mm)	mm	(inch)	mm	(inch)	rei Neel Fackling Qualitity
	SOD-123	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000	

## **Marking information**

"W1" = Part No "III" = Cathode line Font type: Arial



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